

3QL200AK Thru 3QL200AS

1. 外型尺寸Feature & Dimension

Features

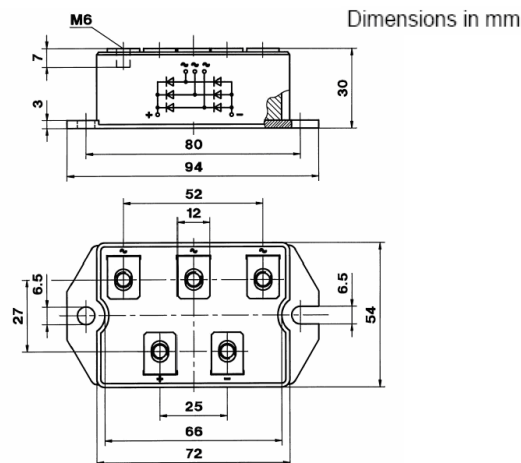
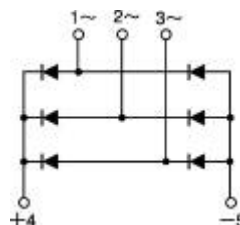
- Package with screw terminals
- Isolation voltage 3000 V~
- Glass passivated chips
- Blocking voltage up to 1600 V
- Low forward voltage drop
- UL registered E231047

Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling



2. 产品性能Product Characteristic

ELECTRICAL AND THERMAL CHARACTERISTICS

TC=25°C unless otherwise specified

Item	Symbol	3QL200AK	3QL200AO	3QL200AQ	3QL200AS	Unit
Maximum repetitive voltage	VRM	800	1200	1400	1600	V
Maximum RMS Voltage	VRMS	560	840	980	1120	V
Maximum DC Blocking Voltage	VDC	800	1200	1400	1600	V
Peak Reverse Current (per leg) @Tj = 25°C	IR	≤10				uA
At Rated DC Blocking Voltage @Tj = 150°C		≤20				mA
Average recified forward current 60Hz sine	Io	200				A
wave,R-load with heatsink Tc=100°C						
TJ=45°C VR=0 t=10ms (50Hz),sine	IFSM	2000				A
t=8.3ms(60Hz),sine		2200				
TJ=150°C VR=0 t=10ms (50Hz),sine		1800				
t=8.3ms(60Hz),sine		1950				
TJ=45°C VR=0 t=10ms (50Hz),sine	I²t	20000				A²s
t=8.3ms(60Hz),sine		24200				
TJ=150°C VR=0 t=10ms (50Hz),sine		16200				
t=8.3ms(60Hz),sine		19010				

3QL200AK Thru 3QL200AS

Storage temperature	Tstg	-40 to +150	℃
50/60Hz RMS t=1 min IISOL≤1mA t=1 s	VISOL	2500 3000	V~
Mounting torque(M5) Terminal connection torque(M5)	Md	(Recommended Value 1.5~2.5) 5±15%	N·m
typical	Weight	270	g
I _F =200A T _J =25℃	V _F	1.3	V
For power-loss calculations only	V _{T0}	0.8	V
per diode DC current Per module	R _{thJC}	0.6 0.1	k/w k/w
per diode DC current(typ.) per module(typ.)	R _{thCS}	0.18 0.03	k/w k/w
Creeping distance on surface	dS	10	mm
Creeping distance in air	dA	9.4	mm
Max. allowable acceleration	a	50	m/s ²

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3. 特性曲线 Characteristic Curve

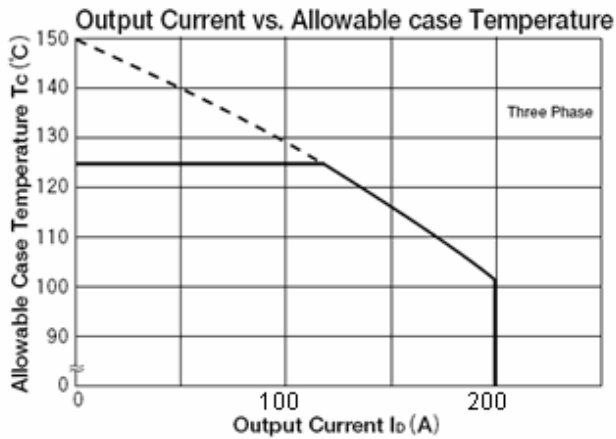


Fig.1. Power dissipation vs. output current

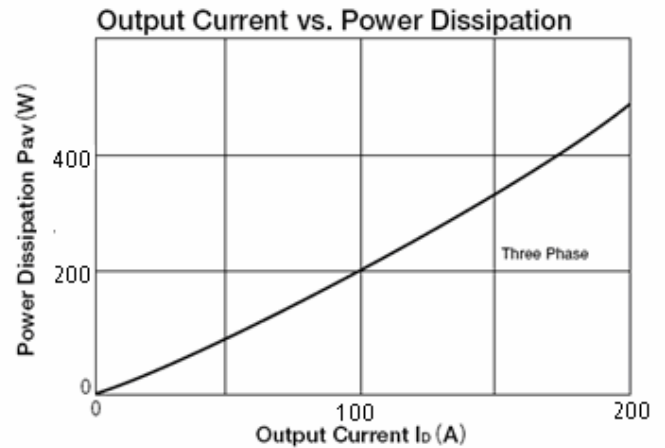


Fig.2. Power dissipation vs. Power Dissipation

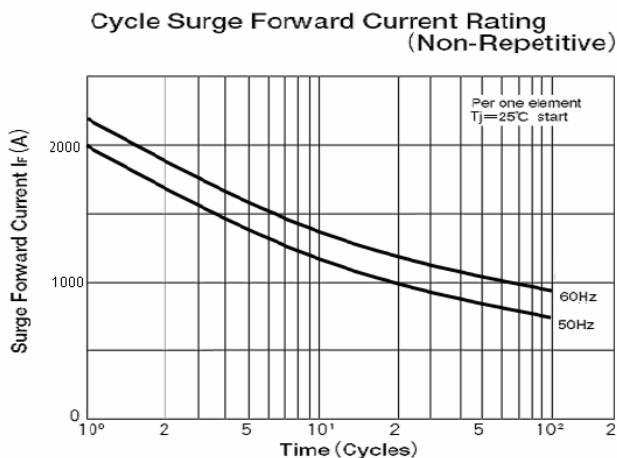


Fig.3. Surge overload characteristics vs. time

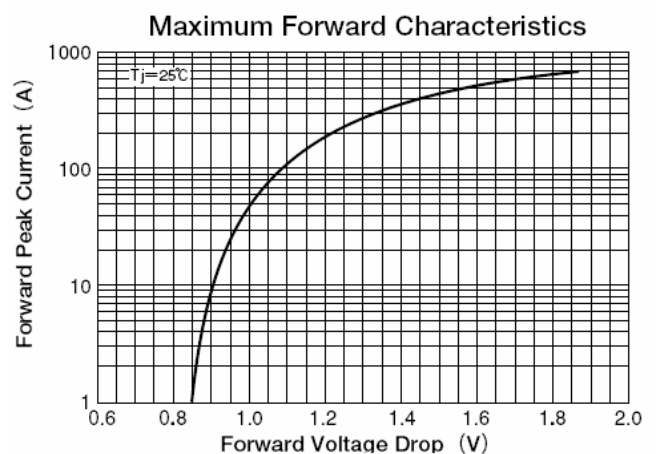


Fig.4. Forward characteristics of a diode arm

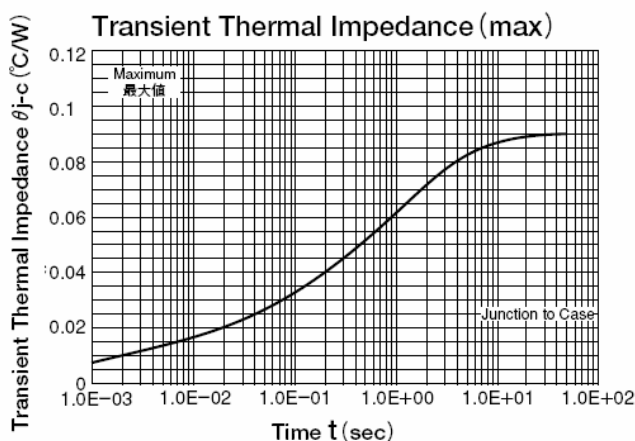
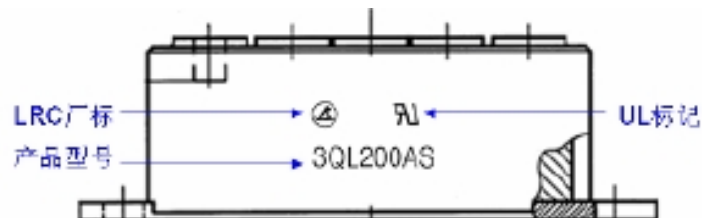


Fig.5. Transient thermal impedance vs. time

3QL200AK Thru 3QL200AS

4. 印字规范 Marking Identification



Note:

型号: 3 QL 200 AS

- Bridge reverse voltage=1600V
- Average rectified forward Current=200A
- mean: QL series bridge
- mean: Three phase bridge